

**1N66A**

**GOLD BONDED GERMANIUM DIODE**

**FEATURES**

- Low forward voltage drop—low power consumption
- Very low noise level
- Metallurgically bonded

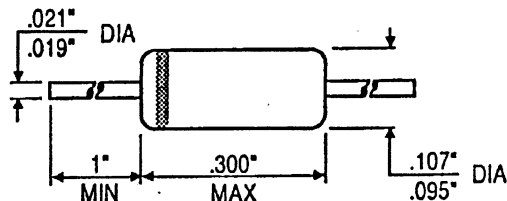
**ABSOLUTE MAXIMUM RATINGS** (at 25 °C, unless otherwise specified)

Peak Inverse Voltage	60 Volts
Peak Forward Current	500 mA
Operating Temperature Range	- 65 °C to 85 °C
Average Power Dissipation	80 mW

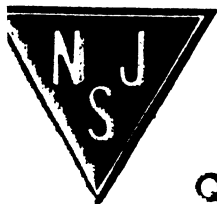
**ELECTRICAL CHARACTERISTICS**

	Symbol	Conditions	Min	Max	Unit	T °C
Peak Inverse Voltage	PIV	1 mA	60		V	25 °C
Reverse Current	I <sub>r</sub>	10 V		50	μA	25 °C
Reverse Current	I <sub>r</sub>	50 V		800	μA	°C
Forward Voltage	V <sub>f</sub>	5 mA		1	V	25 °C

**MECHANICAL**



Passes all mechanical and environmental requirements of MIL-S-19500, including shock and vibration.



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**Quality Semi-Conductors**